# NSN 5961-01-099-9138

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# Inclosure Material:

Metal

# **Overall Length:**

Between 0.250 inches and 0.450 inches

# **Overall Diameter:**

0.875 inches

# **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-3

Electrode Internally-electrically Connected To Case:

Collector

## **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

120.0 breakdown voltage, collector-to-emitter, base open

## **Current Rating Per Characteristic:**

100.00 milliamperes source cutoff current

## **Power Rating Per Characteristic:**

6.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## Test Data Document:

06509-122024-1 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# Terminal Type And Quantity:

1 case and 2 pin

## Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

No

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